

High voltage fast-switching PNP power transistor

Datasheet - production data

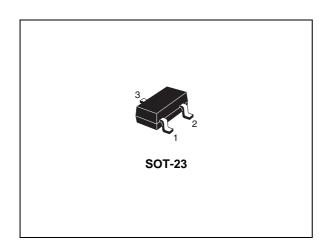
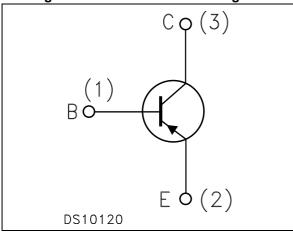


Figure 1. Internal schematic diagram



Features

- Excellent h_{FE} linearity up to 50 mA
- Miniature SOT-23 plastic package for surface mounting circuits
- Tape and reel packaging
- The NPN complementary type is STR1550

Applications

• LED driving

Description

This device is a high voltage fast-switching PNP power transistor, manufactured using high voltage multi-epitaxial planar technology for high switching speeds.

It employs a cellular emitter structure with planar edge termination to enhance switching speeds, while maintaining a wide RBSOA.

Table 1. Device summary

Order code	Marking	Package	Packing
STR2550 R2550		SOT-23	Tape and reel

Contents STR2550

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STR2550 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage (I _E = 0)	-500	V
V _{CEO} Collector-emitter voltage (I _B = 0)		-500	V
V _{EBO} Emitter-base voltage (I _C = 0)		-7	V
I _C	Collector current	-0.5	Α
I _{CM}	Collector peak current (t _P < 5 ms)	-1	Α
P _{TOT}	Total dissipation at T _{amb} = 25 °C	500	mW
T _{STG}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJA} ⁽¹⁾	Thermal resistance junction-ambient max	250	°C/W

^{1.} Device mounted on PCB area of 1 cm².

Electrical characteristics STR2550

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = -500 V			-10	μΑ
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = -100 μA	-500			V
V _{(BR)CEO} (1)	Collector-emitter breakdown voltage (I _B = 0)	I _C = -1 mA	-500			V
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = -100 μA	-7			V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = -20 \text{ mA}$ $I_B = -2 \text{ mA}$ $I_C = -50 \text{ mA}$ $I_B = -10 \text{ mA}$			-0.2 -0.3	V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = -50 mA I _B = -10 mA			-1.0	V
V _{BE(on)}	Base-emitter on voltage	$I_C = -50 \text{ mA}$ $V_{CE} = -10 \text{ V}$			-1.1	V
h _{FE} ⁽¹⁾	DC current gain	$I_{C} = -1 \text{ mA}$ $V_{CE} = -10 \text{ V}$ $I_{C} = -50 \text{ mA}$ $V_{CE} = -10 \text{ V}$ $I_{C} = -100 \text{ mA}$ $V_{CE} = -10 \text{ V}$	100		300	

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2%

2.1 Electrical characteristics (curves)

Figure 2. h_{FE} vs. I_C @ V_{CE} =5 V

Figure 3. h_{FE} vs. I_C @ V_{CE}=10 V

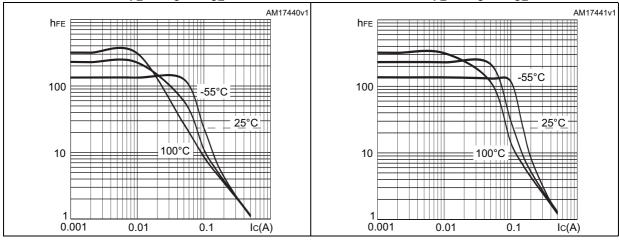


Figure 4. $V_{CE(sat)}$ vs. I_C @ h_{FE} =5

Figure 5. $V_{CE(sat)}$ vs. I_C @ h_{FE} =10

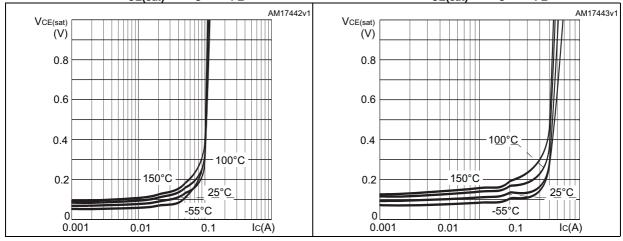
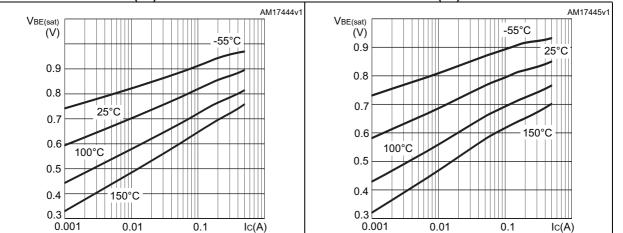


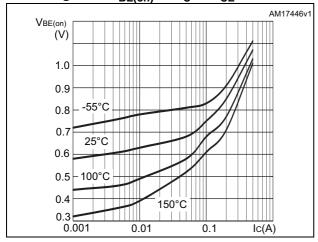
Figure 6. $V_{BE(sat)}$ vs. I_C @ h_{FE} =5

Figure 7. $V_{BE(sat)}$ vs. I_C @ h_{FE} =10



Electrical characteristics STR2550

Figure 8. $V_{BE(on)}$ vs. $I_C @ V_{CE}$ =10 V



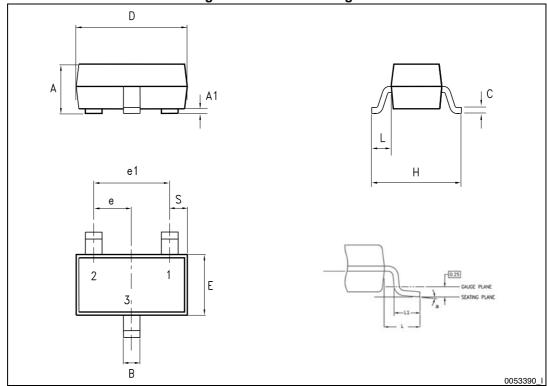
3 Package mechanical data

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Table 5. SOT-23 mechanical data

Dim.	mm			
	Min.	Тур.	Max.	
Α	0.89		1.40	
A1	0		0.10	
В	0.30		0.51	
С	0.085		0.18	
D	2.75		3.04	
е	0.85		1.05	
e1	1.70		2.10	
E	1.20		1.75	
Н	2.10		3.00	
L		0.60		
S	0.35		0.65	
L1	0.25		0.55	
а	0°		8°	

Figure 9. SOT-23 drawings



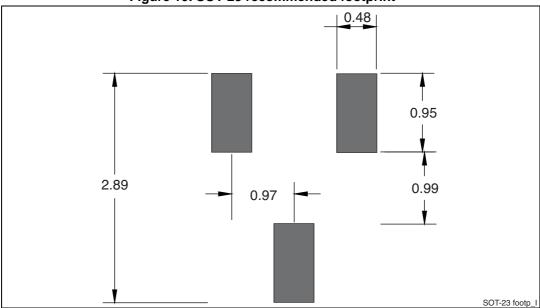


Figure 10. SOT-23 recommended footprint ^(a)

a. Dimensions are in mm.

Revision history STR2550

4 Revision history

Table 6. Document revision history

Date	Revision	Changes
17-Oct-2011	1	Initial release
05-Jun-2012	2	Modified: features, <i>Table 4</i> ($V_{CE(sat)}$ values, h_{FE} test conditions and values)
21-May-2013	3	 Modified: Table 4 (V_{BE(sat)} values and h_{FE} max. value Inserted: V_{BE(on)} Modified: Table 4 (h_{FE} max. value) Added new section: Electrical characteristics (curves)
27-May-2013	4	Document status promoted from preliminary to production data.

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